

NCE P-Channel Super Trench Power MOSFET

Description

The NCEP40PT15G uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

General Features

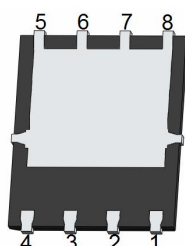
- $V_{DS} = -40V, I_D = -150A$
 $R_{DS(ON)} = 2.8m\Omega$ (typical) @ $V_{GS} = -10V$
 $R_{DS(ON)} = 3.8m\Omega$ (typical) @ $V_{GS} = -4.5V$
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

100% UIS TESTED!
100% ΔVs TESTED!

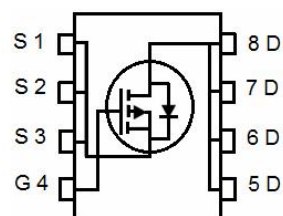
DFN 5X6



Top View



Bottom View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP40PT15G	NCEP40PT15G	DFN5X6-8L	-	-	-

Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-40	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous ($T_C = 25^\circ C$)	$I_D (T_C = 25^\circ C)$	-150	A
Drain Current-Continuous ($T_C = 100^\circ C$)	$I_D (T_C = 100^\circ C)$	-106	A
Drain Current-Continuous ($T_A = 25^\circ C$)	$I_D (T_A = 25^\circ C)$	-20.5	A
Pulsed Drain Current (Note 1)	I_{DM}	-600	A
Maximum Power Dissipation ($T_C = 25^\circ C$)	$P_D (T_C = 25^\circ C)$	150	W
Maximum Power Dissipation ($T_A = 25^\circ C$)	$P_D (T_A = 25^\circ C)$	2.5	W
Derating factor		1.2	W/ $^\circ C$
Single pulse avalanche energy (Note 5)	E_{AS}	1076	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^\circ C$

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	$R_{\theta JC}$	0.83	$^\circ C/W$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	50	$^\circ C/W$

Electrical Characteristics (T_c=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250μA	-40		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1.0	-1.5	-2.2	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-75A	-	2.8	3.5	mΩ
		V _{GS} =-4.5V, I _D =-75A	-	3.9	6.0	mΩ
Gate resistance	R _G	F=1.0MHz	-	5.5	-	Ω
Forward Transconductance	g _{FS}	V _{DS} =-5V, I _D =-75A	-	30	-	S
Dynamic Characteristics (Note 4)						
Input Capacitance	C _{iss}	V _{DS} =-20V, V _{GS} =0V, F=1.0MHz	-	8940	-	PF
Output Capacitance	C _{oss}		-	1900	-	PF
Reverse Transfer Capacitance	C _{rss}		-	45	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =-20V, I _D =-75A V _{GS} =-10V, R _G =1.6Ω	-	18	-	nS
Turn-on Rise Time	t _r		-	13	-	nS
Turn-Off Delay Time	t _{d(off)}		-	90	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Q _g	V _{DS} =-20V, I _D =-75A, V _{GS} =-10V	-	104.4	-	nC
Gate-Source Charge	Q _{gs}		-	20.8		nC
Gate-Drain Charge	Q _{gd}		-	13.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V, I _S =-75A	-		-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-150	A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = -75A	-		35	nS
Reverse Recovery Charge	Q _{rr}	di/dt = 100A/μs (Note 3)	-		85	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production
5. EAS condition : T_J=25°C, V_{DD}=-20V, V_G=-10V, L=0.5mH, R_G=25Ω

Typical Electrical and Thermal Characteristics

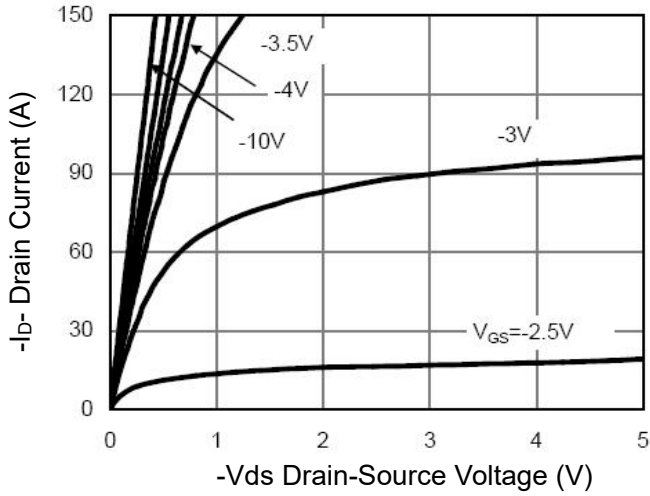


Figure 1 Output Characteristics

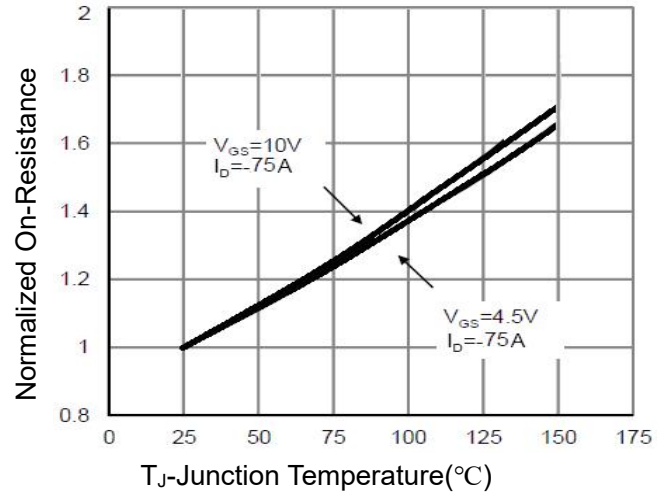


Figure 4 R_{DS(on)}-Junction Temperature

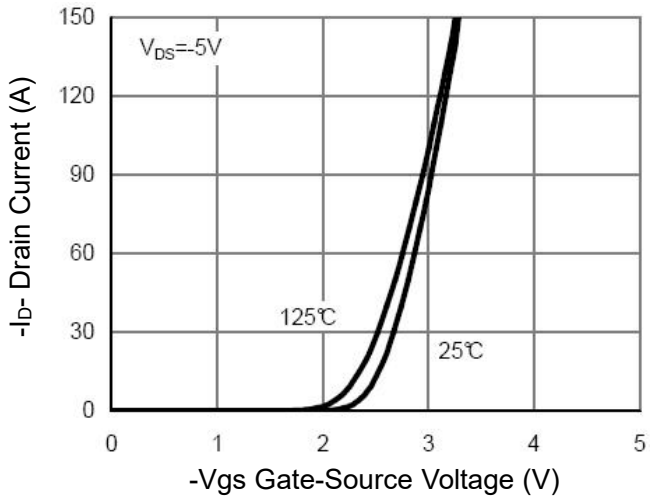


Figure 2 Transfer Characteristics

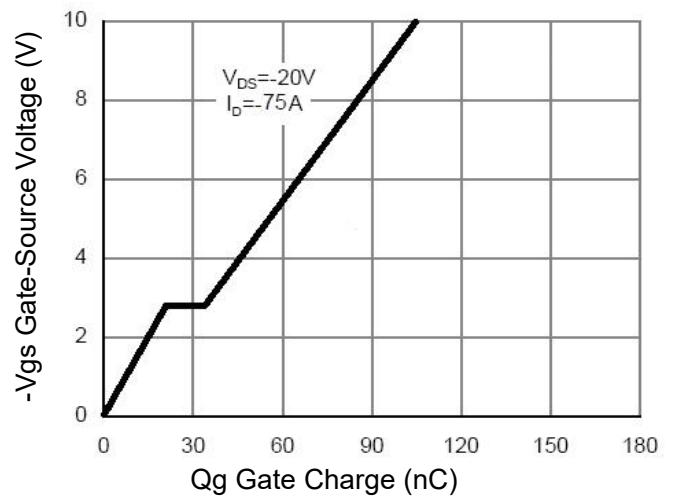


Figure 5 Gate Charge

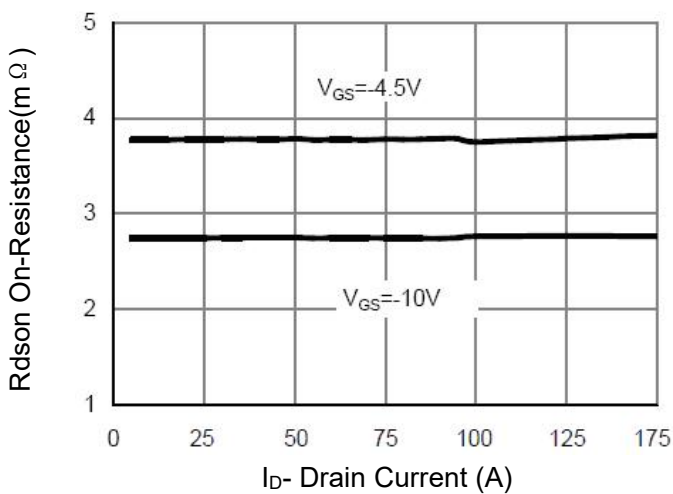


Figure 3 R_{DS(on)}- Drain Current

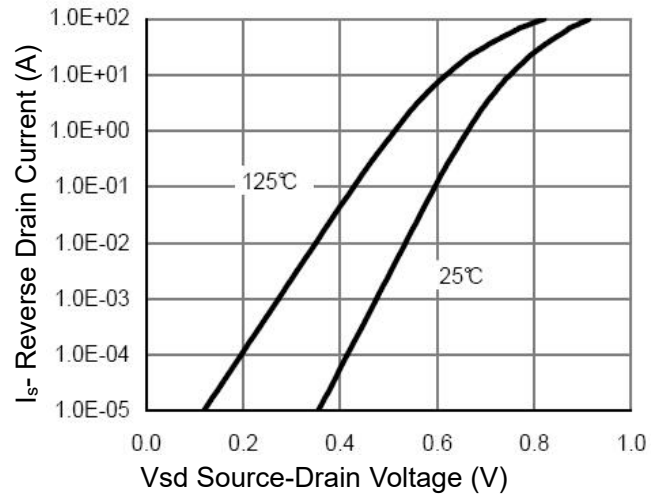


Figure 6 Source- Drain Diode Forward

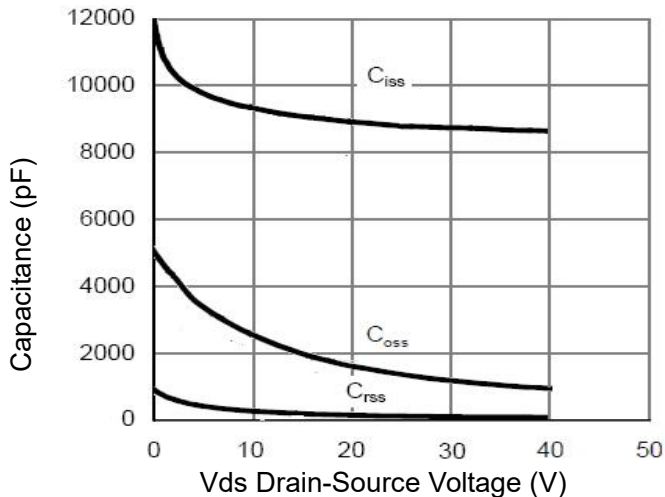


Figure 7 Capacitance vs Vds

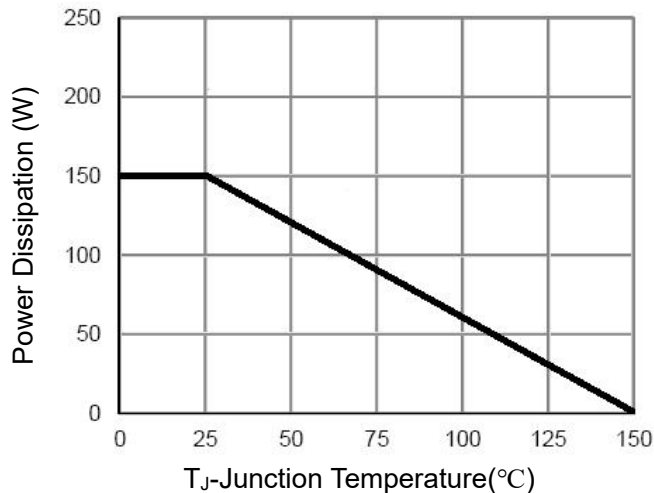


Figure 9 Power De-rating

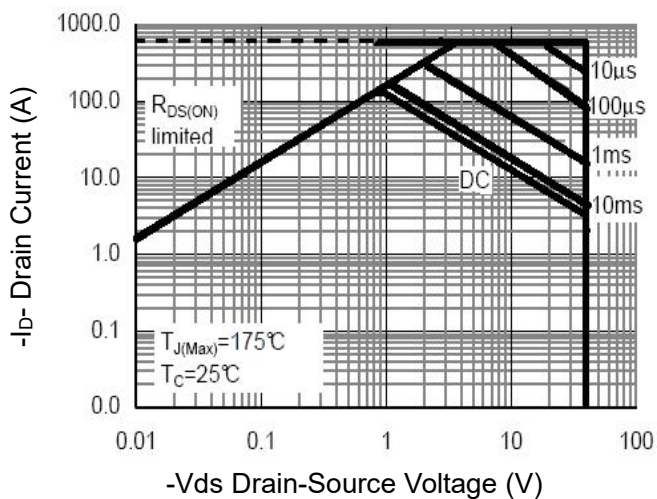


Figure 8 Safe Operation Area

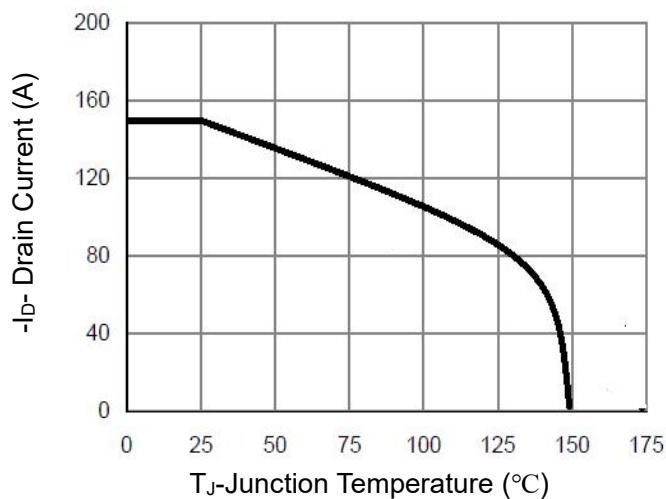


Figure 10 Current De-rating

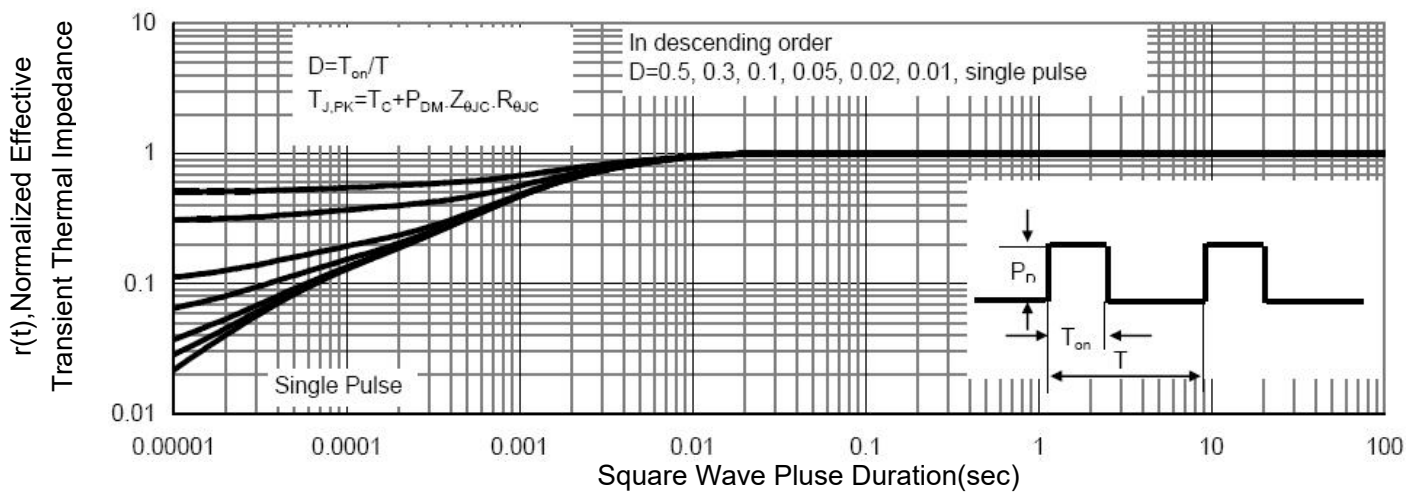
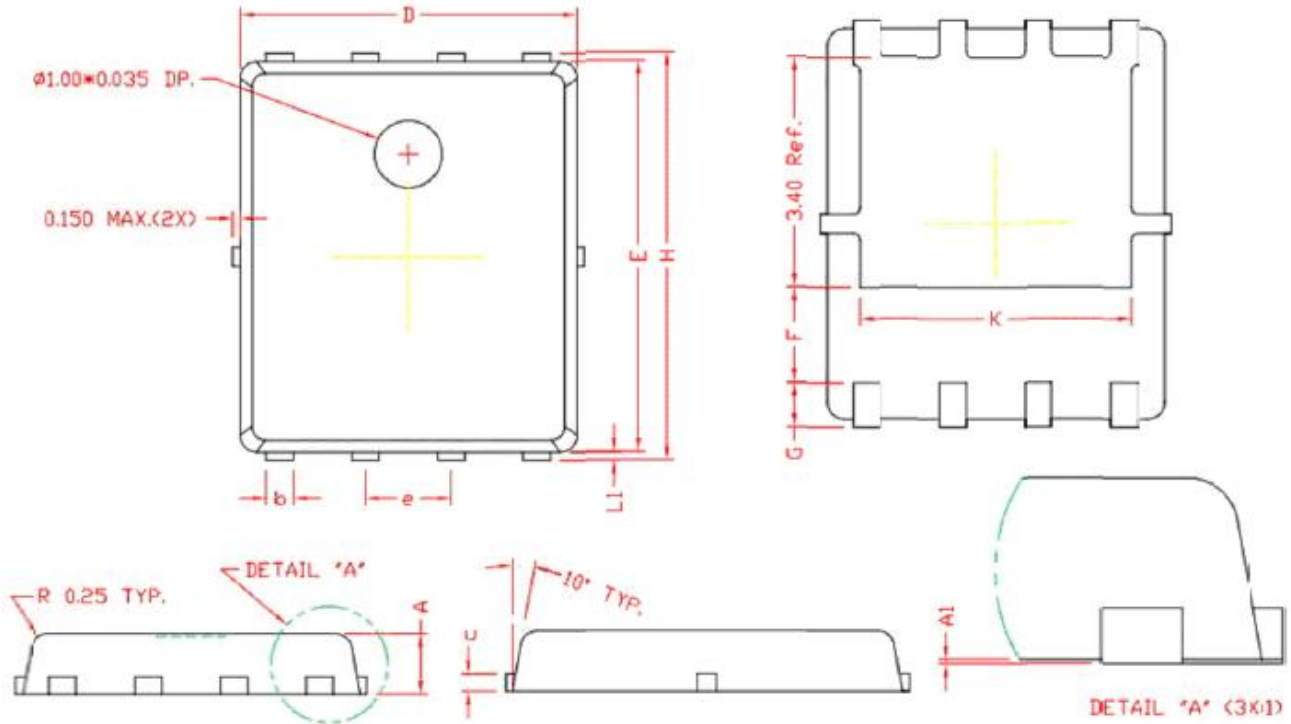


Figure 11 Normalized Maximum Transient Thermal Impedance

DFN5X6-8L Package Information



COMMON DIMENSIONS

(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NCM	MAX
A	0.80	0.90	1.00
A1	0.00	0.03	0.05
b	0.35	0.42	0.49
c	0.254 REF.		
D	4.90	5.00	5.10
F	1.40 REF.		
E	5.70	5.80	5.90
e	1.27 BSC.		
H	5.95	6.08	6.20
L1	0.10	0.14	0.18
G	0.60 REF.		
K	4.00 REF.		

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